NSN 5962-01-171-7451

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View Online at https://aerobasegroup.com/nsn/5962-01-171-7451

Body Length:

Between 0.335 inches and 0.400 inches

Body Width:

Between 0.335 inches and 0.400 inches

Body Height:

0.090 inches

Maximum Power Dissipation Rating:

1225.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Bipolar and electrostatic sensitive and programmed and burn in

Inclosure Material:

Ceramic or metal

Inclosure Configuration:

Flat pack

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

12 input

Terminal Surface Treatment:

Gold

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Memory Device Type:

Rom

Precious Material And Location:

Terminal surface option gold

Precious Material:

Gold

Test Data Document:

82577-932750 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

18 flat leads

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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